# **Monolithic Amplifier**

TSS-13LN+

 $50\Omega$  1MHz to 1 GHz

#### CASE STYLE: DQ1225

### **The Big Deal**

- Ultra-High IP3, +39.2 dBm typ.
- Low supply voltage, 3 to 5V
- Excellent Noise Figure, 1.1 dB typ.
- Shutdown feature

### **Product Overview**

TSS-13LN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-13LN+ has good input and output return loss over a broad frequency range. TSS-13LN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

### **Key Features**

Feature	Advantages
Broad Band: 1MHz to 1GHz	Broadband covering primary wireless communications bands: VHF, UHF, Cellular
Extremely High IP3 38.4 dBm typical at 1 MHz 39.2 dBm typical at 0.5 GHz	The TSS-13LN+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being approximately 11-18 dB above the P1dB point. This feature makes this amplifier ideal for use in:  • Driver amplifiers for complex waveform up converter paths  • Drivers in linearized transmit systems  • Secondary amplifiers in ultra-High Dynamic range receivers
Shutdown feature	Allow users to turn on and off the amplifier with pulsed signals while keeping the power supply at constant voltage to minimize DC power consumption
Low Noise Figure 1.1 dB at 0.5 GHz	Enables lower system noise figure performance and along with High OIP3 provides high dynamic range
Low Supply Voltage	TSS-13LN+ supports low supply voltage operation which indicate low power consumption.

### **Product Features**

- High IP3, 39.2 dBm typ. at 0.5 GHz
- Gain, 22.8 dB typ. at 0.5 GHz
- Low noise figure, 1.1 dB at 0.5 GHz
- Low voltage, 5V and 3V
- Shutdown feature

### **Typical Applications**

- Base station infrastructure
- CATV
- Cellular

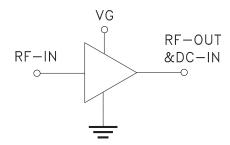


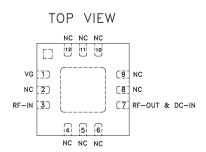
+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

### **General Description**

TSS-13LN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-13LN+ has good input and output return loss over a broad frequency range. TSS-13LN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

### simplified schematic and pad description





Function	Pin Number	Description
RF IN	3	RF Input
RF-OUT and DC-IN	7	RF Output and DC Bias
GND	Paddle	Connections to ground.
NC	2, 4-6, 8-12	No connection, grounded externally
VG	1	Control voltage for shutdown (VG)

## Electrical Specifications $^1$ at 25 $^{\circ}$ C & 50 $\Omega$ , unless noted

Parameter	Condition (MHz)	Amplifier-ON  VDD = 5V			Amplifier- OFF	Amplifier- ON	Amplifier- OFF VDD = 3V	Units
					VDD = 5V	VDD = 3V		
		Min.	Тур.	Max.	Тур.	Тур.	Тур.	
Frequency Range		1		1000	1-1000	1-1000	1-1000	MHz
	1		3.1			3.0		dB
	20		1.1			1.1		
Noise Figure	250		1.1			1.1		
	500		1.1			1.1		
	1000		1.2			1.3		
	1	22.1	24.7	27.1	-24	23.9	-24	dB
	20	_	24.2	_	-22	23.5	-22	
Gain	250	20.6	23.0	25.2	-21	22.3	-21	
	500	_	22.8	_	-22	21.9	-22	
	1000	18.2	20.9	22.2	-27	19.5	-27	
Reversed Isolation	1-1000		26		27	26	27	dB
	1		11		12	10	12	dB
	20		15		12	15	12	
Input Return Loss	250		18		12	19	12	
	500		21		12	17	12	
	1000		14		10	10	10	
	1		11		1	11	1	dB
	20		19		2	21	2	
Output Return Loss	250		18		2	21	2	
	500		25		2	21	2	
	1000		11		2	10	2	
	1		20.3			14.2		dBm
	20		22.4			16.3		
Output Power @1dB compression AMP-ON	250		24.1			19.3		
	500		24.5			19.5		
	1000		23.4			18.3		
	1	_	38.4			31.6		dBm
	20	_	40.3			33.2		
Output IP3 (Pout = 0dBm/Tone)	250	_	39.6			34.4		
	500	35.4	39.2			33		
	1000	_	36.2			29.4		
Device Operating Voltage (VDD)		4.75	5	5.25	5	3	3	V
Device Operating Current (ID)			142	151	5	72	3	mA
Control Voltage (VG)			0		5	0	5	V
DC Current (ID) Variation Vs. Temperature <sup>2</sup>			10			33		uA/degC
DC Current(ID) Variation Vs. Voltage			0.025			0.033		mA/mV

<sup>1.</sup> Measured on Mini-Circuits Characterization test board TB-TSS-13LN+. See Characterization Test Circuit (Fig. 1) 2. (Current at  $105^{\circ}$ C — Current at  $-45^{\circ}$ C)/150

### Absolute Maximum Ratings<sup>3</sup>

Parameter	Ratings		
Operating Temperature (ground lead)	-40°C to 105°C		
Storage Temperature	-65°C to 150°C		
Total Power Dissipation	3.3W		
Input Power	28 dBm (5 minutes max.) 6 dBm (continuos) for 1- 30 MHz 10 dBm (continuos) for 0.03-1 GHz		
DC Voltage V <sub>DD</sub> <sup>4</sup> (Pad 7)	10V		
DC Voltage V <sub>G</sub> <sup>5</sup> (Pad 1)	10V		

 $<sup>^3</sup>$  Permanent damage may occur if these limits are exceeded.  $^4$  Measured by keeping V<sub>0</sub>=0V.  $^5$  Measured by keeping V<sub>0</sub>=5V.

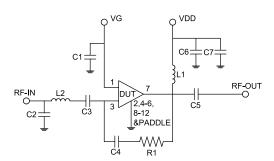
### Control Voltage (V<sub>G</sub>) Fig. 1

	Min.	Тур.	Max.	Units
Amplifier-ON	_	0	0.7	V
Amplifier-OFF	1.9	5	_	V

### **Switching Specifications**

Parameter	5V Typ.	3V Typ.	Units	
Amplifian ON to Chutdour	OFF TIME (50% Control to 10% RF)		6.2	μs
Amplifier ON to Shutdown	FALL TIME (90 to 10% RF) 7.4		3.6	
A life Objet A ON	ON TIME (50% Control to 90% RF)	95.2	144.7	_
Amplifier Shutdown to ON	RISE TIME (10% to 90% RF) 60.0		200.7	μS
Control Voltage Leakage			311.0	mV

### **Characterization Test Circuit / Recommended Application Circuit**



Component	Size	Value	Part Number	Manufacturer
C1	0402	0.1uF	GRM155R71C104KA88D	Murata
C2	0402	1.5pF	GRM1555C1H1R5CA1D	Murata
C3	0603	2.2uF	GRM188C71E225KE11D	Murata
C4	0402	0.1uF	GRM155R71C104KA88D	Murata
C5	0603	2.2uF	GRM188C71E225KE11D	Murata
C6	0402	1000pF	GRM1555C1H102JA01D	Murata
C7	0805	10uF	GRM21BC71E106KE11L	Murata
L1	1210	15uH	LQH32DN150K53L	Murata
L2	0603	5.1nH	0603CS-5N1XJLU	Coilcraft
R1	0402	1.5K0hm	RK73H1ETTP1501F	Koa

Fig 1. Block diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-TSS-13LN+) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

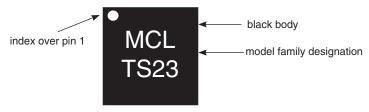
#### Conditions:

- 1. Gain and Return Loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +0dBm/tone at output.
- 3. Switching Time

RF Signal: Pin=-25 dBm, f<sub>RF</sub>=500 MHz.

 $V_{DD}$ =3 & 5V DC,  $V_{G}$ =Pulse signal at 1 KHz with  $V_{HIGH}$ =5V,  $V_{LOW}$ =0V, 50% duty cycle.

### **Product Marking**

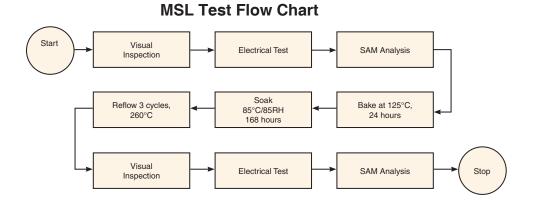


Marking may contain other features or characters for internal lot control

Additional Detailed Technical Information additional information is available on our dash board. To access this information click here			
	Data Table		
Performance Data	Swept Graphs		
	S-Parameter (S2P Files) Data Set (.zip file)		
Case Style	DQ1225 Plastic package, exposed paddle lead finish: Matte-Tin		
Tape & Reel	F66		
Standard quantities available on reel	7" reels with 20, 50, 100, 200, 500 or 1K devices		
Suggested Layout for PCB Design	PL-623		
Evaluation Board	TB-TSS-13LN+		
Environmental Ratings	ENV08T9		

### **ESD Rating**

Human Body Model (HBM): Class 1A (Pass 250 V) in accordance with ANSI/ESD STM 5.1 - 2001



#### **Additional Notes**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms");
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